





Memory Depth	Simulation		Analytical	
	IBL	10xLHC	IBL	10xLHC
5	0.047%	2.19%	0.029%	2.25%
6	6.07%	0.65%	0.003%	0.57%
7	<0.01%	0.16%	<0.01%	0.13%

Simulation type	Power (avg) [uW]	
type 1	42.28	
type 2	25.19	
type 3	24.69	
type 4	24.73	@1.2
type 5	35.12	



Tomasz Hemperek, University of Bonn, Germany, D. Arutinov, M. Barbero, M. Karagounis, A. Kruth, N. Wermes, Bonn Germany; D. Fougeron, M. Menouni, CPPM France; R. Beccherle, G. Darbo, INFN Genova Italy; S. Dube, D. Ellege, R. Ely, M. Garcia-Sciveres, D. Gnani, A. Mekkaoui, LBNL USA; V. Gromov, R. Kluit, J. Schipper, NIKHEF Netherlands.





